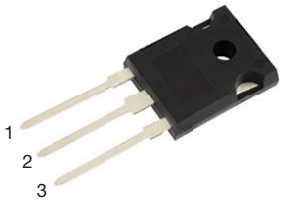
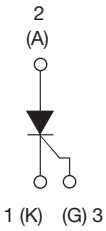
Thyristor High Voltage, Phase Control SCR, 40 A



TO-247AD 3L



FEATURES

- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification
- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-40TPS... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

PRIMARY CHARACTERISTICS	
$I_{T(AV)}$	35 A
V_{DRM}/V_{RRM}	1200 V
V_{TM}	1.45 V
I_{GT}	150 mA
T_J	-40 °C to +150 °C
Package	TO-247AD 3L
Circuit configuration	Single SCR

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$	Sinusoidal waveform	35	A
I_{RMS}		55	
V_{RRM}/V_{DRM}		1200	V
I_{TSM}		600	A
V_T	40 A, T_J = 25 °C	1.45	V
dv/dt		1000	V/µs
di/dt		100	A/µs
T_J		-40 to +150	°C

VOLTAGE RATINGS			
PART NUMBER	V_{RRM} / V_{DRM}, MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} / I_{DRM} AT 150 °C mA
VS-40TPS12LHM3	1200	1300	20

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**VALUES**	**UNITS**
Maximum average on-state current	$I_{T(AV)}$	T_C = 104 °C, 180° conduction half sine wave		35	A
Maximum continuous RMS on-state current as AC switch	$I_{T(RMS)}$			55	
Maximum peak, one-cycle non-repetitive surge current	I_{TSM}	10 ms sine pulse, rated V_{RRM} applied	Initial $T_J = T_J$ max.	500	
		10 ms sine pulse, no voltage reapplied		600	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied		1250	A^2s
		10 ms sine pulse, no voltage reapplied		1760	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 ms to 10 ms, no voltage reapplied		17 600	$A^2\sqrt{s}$
Low level value of threshold voltage	$V_{T(TO)1}$	T_J = 125 °C		1.02	V
High level value of threshold voltage	$V_{T(TO)2}$			1.23	
Low level value of on-state slope resistance	r_{t1}			9.74	mΩ
High level value of on-state slope resistance	r_{t2}			7.50	
Maximum peak on-state voltage	V_{TM}	110 A, T_J = 25 °C		1.85	V
Maximum rate of rise of turned-on current	di/dt	T_J = 25 °C		100	A/µs
Maximum holding current	I_H	Anode supply = 6 V, resistive load, initial T_J = 1 A, I_T = 25 °C		300	mA
Maximum latching current	I_L	Anode supply = 6 V, resistive load, T_J = 25 °C		350	
Maximum reverse and direct leakage current	I_{RRM}/I_{DRM}	T_J = 25 °C	V_R = rated V_{RRM}/V_{DRM}	0.5	
		T_J = 150 °C		20	
Maximum rate of rise of off-state voltage	dv/dt	T_J = 150 °C, linear to 80 % V_{DRM}, R_g- k = 100 Ω		1000	V/µs

TRIGGERING					
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**VALUES**	**UNITS**
Maximum peak gate power	P_{GM}			10	W
Maximum average gate power	$P_{G(AV)}$			2.5	
Maximum peak gate current	I_{GM}			2.5	A
Maximum peak negative gate voltage	$-V_{GM}$			10	V
Maximum required DC gate voltage to trigger	V_{GT}	T_J = -40 °C	Anode supply = 6 V resistive load	2.0	V
		T_J = 25 °C		1.7	
		T_J = 150 °C		1.2	
Maximum required DC gate current to trigger	I_{GT}	T_J = -40 °C	Anode supply = 6 V resistive load	200	mA
		T_J = 25 °C		150	
		T_J = 150 °C		70	
Maximum DC gate voltage not to trigger	V_{GD}	T_J = 125 °C, V_{DRM} = rated value		0.25	V
Maximum DC gate current not to trigger	I_{GD}			6	mA

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	0.6	°C/W
Maximum thermal resistance, junction to ambient		R_{thJA}		40	
Maximum thermal resistance, case to heat sink		R_{thCS}	Mounting surface, smooth and greased	0.2	
Approximate weight				6	g
				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style TO-247AD 3L	40TPS12LH	

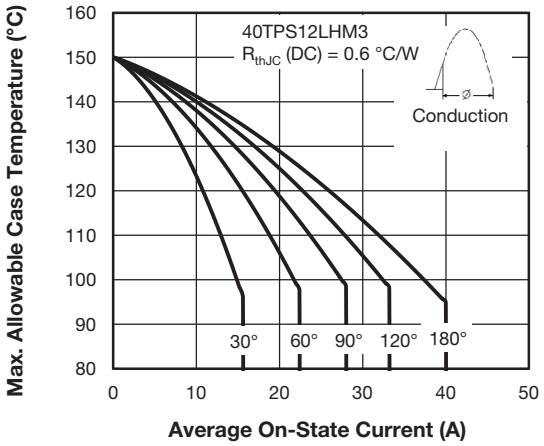


Fig. 1 - Current Rating Characteristics

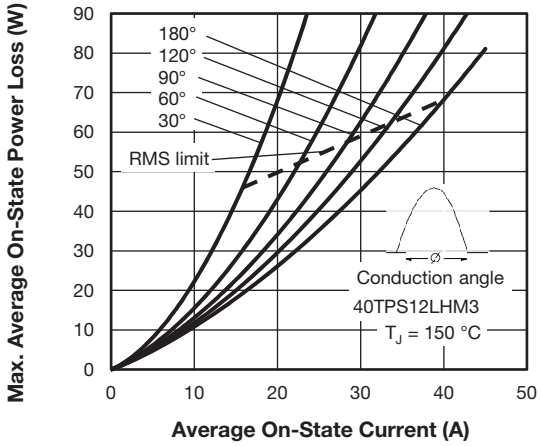


Fig. 3 - On-State Power Loss Characteristics

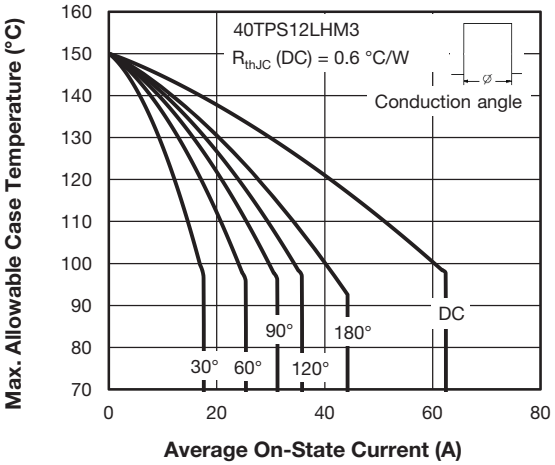


Fig. 2 - Current Rating Characteristics

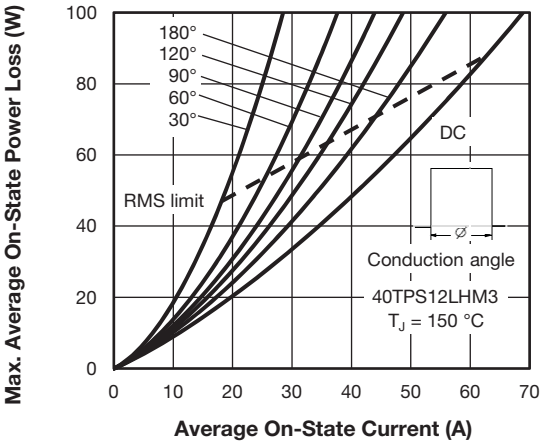


Fig. 4 - On-State Power Loss Characteristics

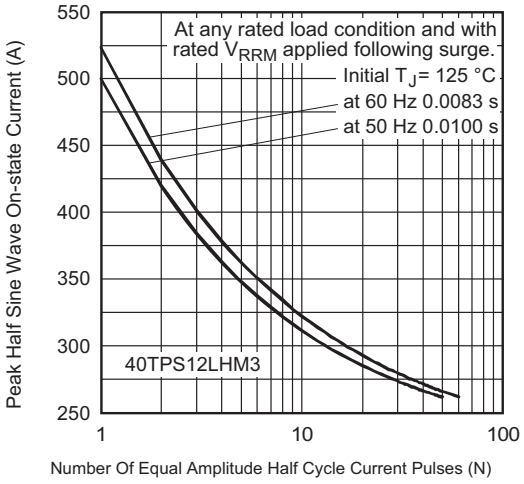


Fig. 5 - Maximum Non-Repetitive Surge Current

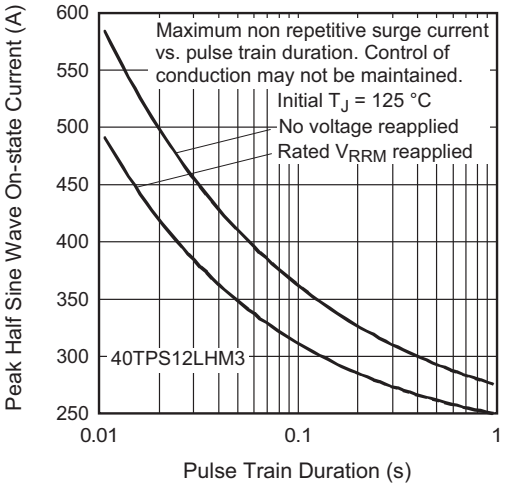


Fig. 6 - Maximum Non-Repetitive Surge Current

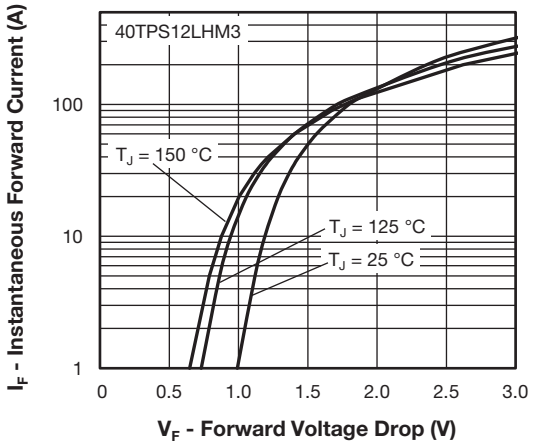


Fig. 7 - On-State Voltage Drop Characteristics

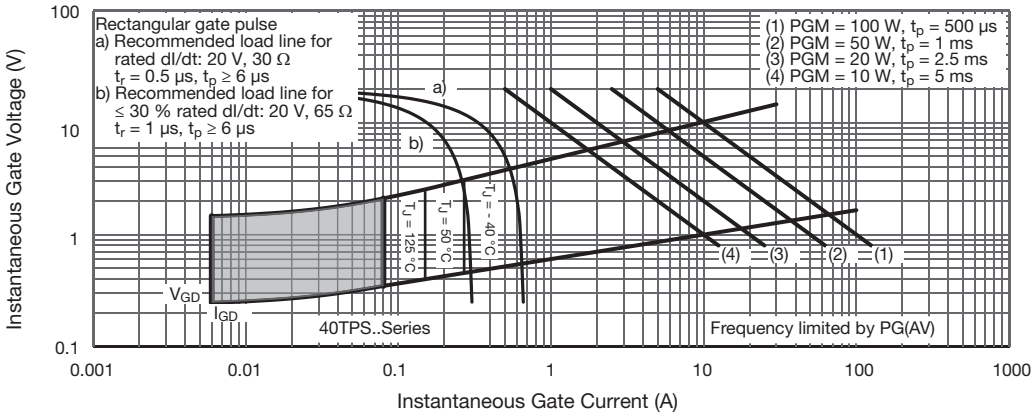


Fig. 8 - Gate Characteristics

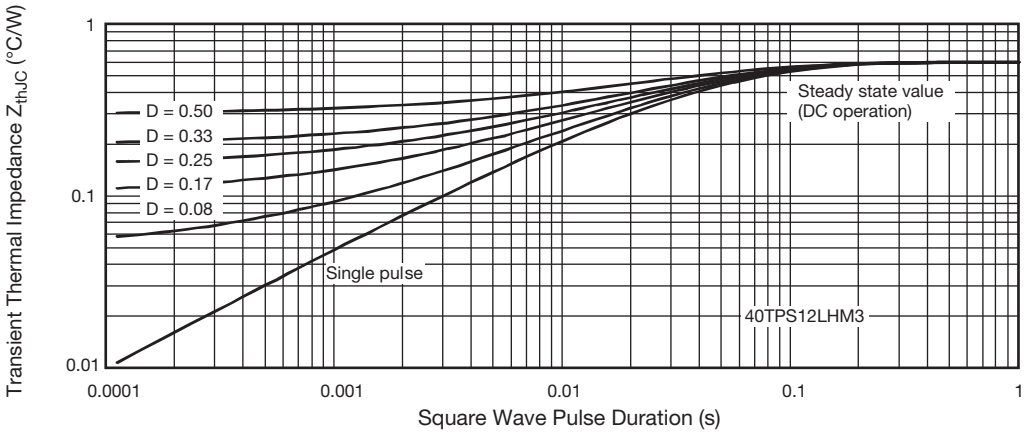


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code

VS-	40	T	P	S	12	A	L	H	M3
1	2	3	4	5	6	7	8	9	10

1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

3 - Circuit configuration:
T = thyristor

4 - Package:
P = TO-247

5 - Type of silicon:
S = standard recovery rectifier

6 - Voltage ratings — 12 = 1200 V

7 - • A = Low Igt selection 40 mA maximum
• None = standard Igt selection

8 - L = long leads

9 - H = AEC-Q101 qualified

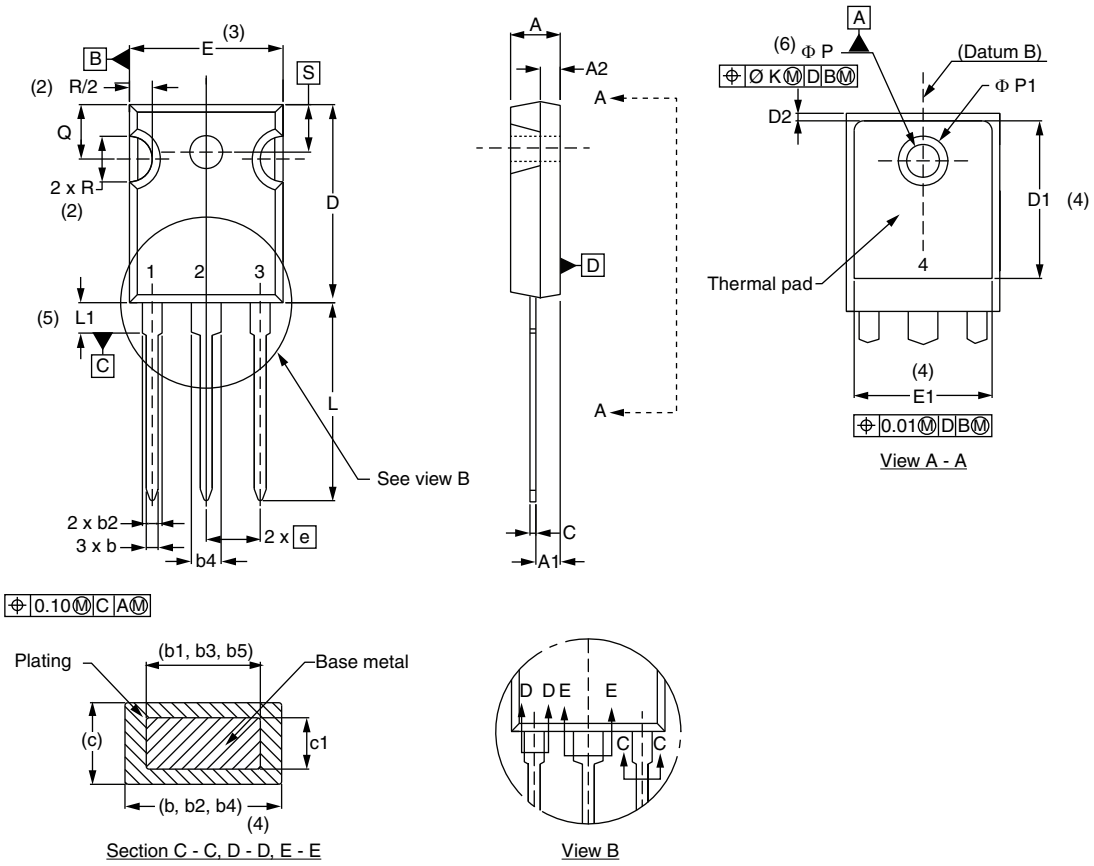
10 - Environmental digit:
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	**QUANTITY PER TUBE**	**MINIMUM ORDER QUANTITY**	**PACKAGING DESCRIPTION**
VS-40TPS12LHM3	25	500	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007

TO-247AD 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
Ø K	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
Ø P	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

Notes

(1) Dimensioning and tolerancing per ASME Y14.5M-1994
(2) Contour of slot optional
(3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
(4) Thermal pad contour optional with dimensions D1 and E1
(5) Lead finish uncontrolled in L1
(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
(7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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